

**Key Parameters**

$V_{RRM}$	1600V
$I_{FAVM}$	226A ( $T_C = 85^\circ\text{C}$ )
$I_{FSM}$	5750A
$V_{T0}$	0,85V
$r_T$	0,95m $\Omega$
$R_{thJC}$	0,14K/W
Base plate	34mm
Weight	165g



For type designation please refer to actual short form catalog

<http://www.ifbip.com/catalog>

**Merkmale**

- Löt-Bond Technologie
- Industrie-Standard-Gehäuse
- Elektrisch isolierte Bodenplatte

**Features**

- Solder-Bond Technology
- Industrial standard package
- Electrically insulated base plate

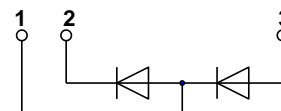
**Typische Anwendungen**

- Gleichrichter für Antriebsapplikationen
- Gleichrichter für UPS
- Batterieladegleichrichter

**Typical Applications**

- Rectifier for drives applications
- Rectifiers for UPS
- Battery chargers

	DMX code digit	DMX code digit quantity
content of customer DMX code	1..18	18
type designation	19..23	5
serial number	24..31	8
internal production order number	32..41	10
material number	42..45	4
date code (YY/WW)	46	1
add on for date code		



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## Technische Information / technical information



**Netz-Dioden-Modul**  
**Rectifier Diode Module**

# DD180N16S

Infineon Technologies Bipolar  
GmbH & Co. KG

### Elektrische Eigenschaften / Electrical properties

Höchstzulässige Werte / Maximum rated values

Periodische Spitzensperrspannung repetitive peak reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj\text{max}}$	$V_{RRM}$	1600	V
Stoßspitzensperrspannung non-repetitive peak reverse voltage	$T_{vj} = +25^{\circ}\text{C} \dots T_{vj\text{max}}$	$V_{RSM}$	1700	V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		$I_{FRMSM}$	275	A
Dauergrenzstrom average on-state current	$T_C = 85^{\circ}\text{C}$ $T_C = 100^{\circ}\text{C}$	$I_{FAVM}$	226 174	A A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj\text{max}}, t_p = 10\text{ms}$	$I_{FSM}$	5750 5000	A A
Grenzlastintegral $I^2t$ -value	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj\text{max}}, t_p = 10\text{ms}$	$I^2t$	165313 125000	A <sup>2</sup> s A <sup>2</sup> s

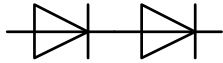
### Charakteristische Werte / Characteristic values

Durchlaßspannung on-state voltage	$T_{vj} = T_{vj\text{max}}, I_F = 500\text{A}$	$V_F$	max. 1,39	V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj\text{max}}$	$V_{(TO)}$	max. 0,85	V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj\text{max}}$	$r_T$	max. 0,95	mΩ
Sperrstrom reverse current	$T_{vj} = T_{vj\text{max}}, V_R = V_{RRM}$	$i_R$	max. 1	mA
Isolations-Prüfspannung insulation test voltage	RMS, $f = 50\text{Hz}, t = 1\text{ sec}$ RMS, $f = 50\text{Hz}, t = 1\text{ min}$	$V_{ISOL}$	3,6 3	kV kV

### Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resistance, junction to case	pro Modul / per Module, $\Theta = 180^{\circ}\text{ sin}$	$R_{thJC}$	max. 0,08	K/W
	pro Zweig / per arm, $\Theta = 180^{\circ}\text{ sin}$		max. 0,16	K/W
	pro Modul / per Module, DC	max. 0,07	max. 0,07	K/W
	pro Zweig / per arm, DC		max. 0,14	K/W
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	pro Modul / per Module	$R_{thCH}$	max. 0,04	K/W
	pro Zweig / per arm		max. 0,08	K/W
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\text{max}}$	135	°C
Betriebstemperatur operating temperature		$T_{c\text{op}}$	- 40...+135	°C
Lagertemperatur storage temperature		$T_{stg}$	- 40...+135	°C

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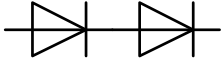
Netz-Dioden-Modul  
Rectifier Diode Module

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**Mechanische Eigenschaften / Mechanical properties**

Gehäuse, siehe Anlage case, see annex			Seite 4 page 4	
Innere Isolation internal insulation	Basisisolierung (Schutzklasse 1, EN 61140) Basic insulation (class 1, IEC 61140)		Al <sub>2</sub> O <sub>3</sub>	
Anzugsdrehmoment für mechanische Anschlüsse mounting torque	Toleranz ±15%	M1	5	Nm
Anzugsdrehmoment für elektrische Anschlüsse terminal connection torque	Toleranz ±10%	M2	5	Nm
Gewicht weight		G	typ. 165	g
Kriechstrecke creepage distance			10	mm
Schwingfestigkeit vibration resistance	f = 50Hz		50	m/s <sup>2</sup>
	file-No.		E 83335	



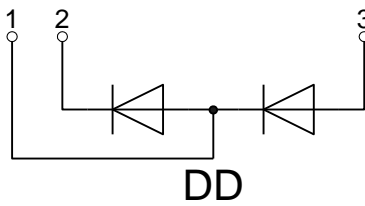
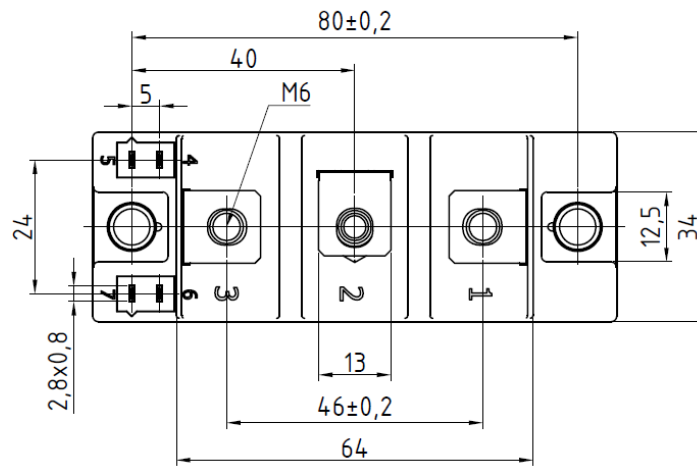
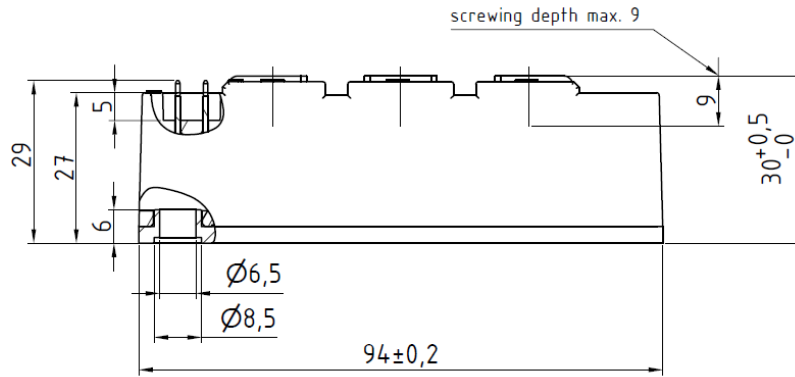
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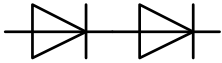


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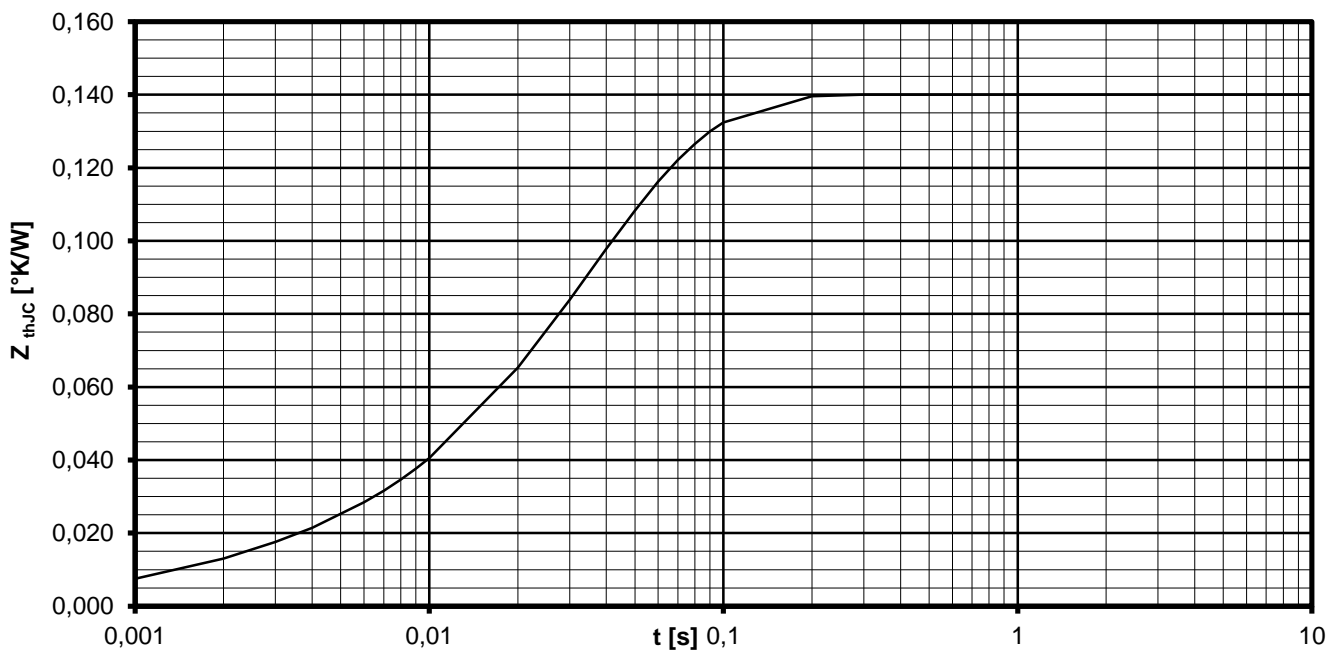


**Analytische Elemente des transienten Wärmewiderstandes  $Z_{thJC}$  für DC**  
**Analytical elements of transient thermal impedance  $Z_{thJC}$  for DC**

Pos. n	1	2	3	4	5	6	7
$R_{thn}$ [K/W]	0,0624	0,0024648	0,0674976	0,0076896			
$\tau_n$ [s]	0,035107	0,035092	0,034917	0,001473			

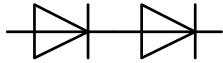
Analytische Funktion / Analytical function:

$$Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} \left( 1 - e^{-\frac{t}{\tau_n}} \right)$$



**Transienter innerer Wärmewiderstand je Zweig / Transient thermal impedance per arm  $Z_{thJC} = f(t)$**

Parameter: Stromflußwinkel  $\Theta$  / Current conduction angle  $\Theta$



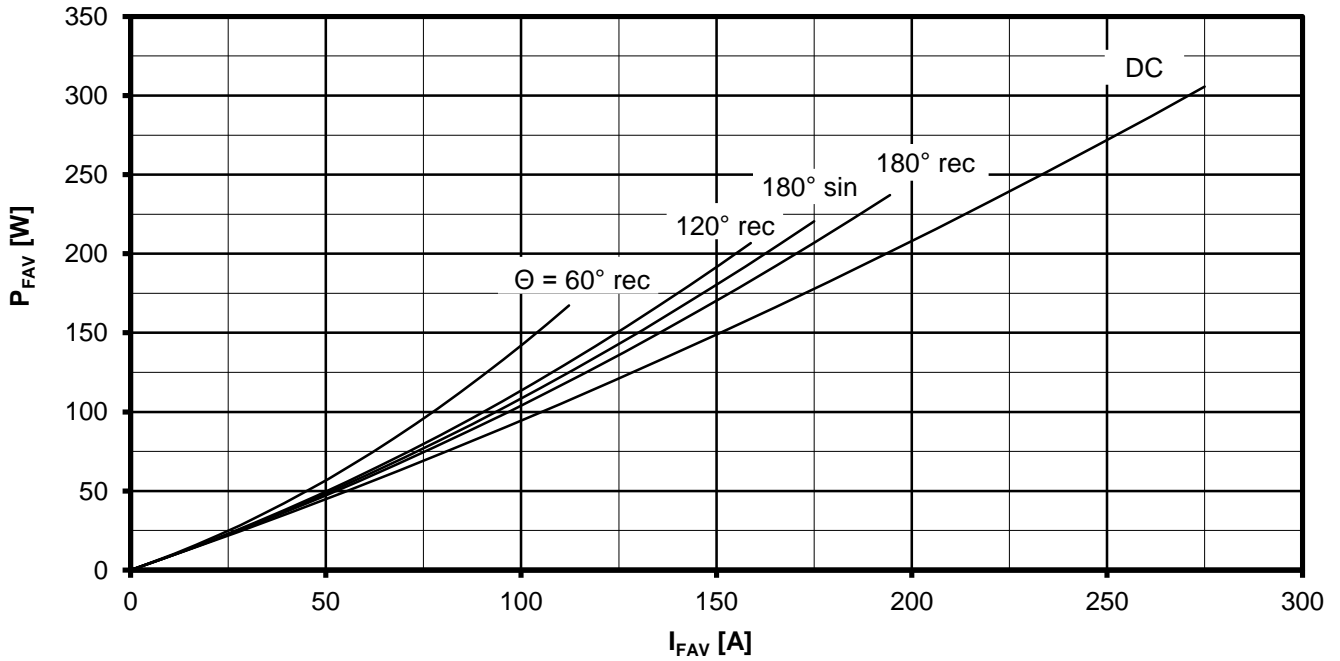
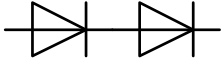
**Erhöhung des  $Z_{th DC}$  bei Sinus und Rechteckströmen mit unterschiedlichen Stromflusswinkeln  $\Theta$**   
**Rise of  $Z_{th DC}$  for sinewave and rectangular current with different current conduction angles  $\Theta$**

$\Delta Z_{th \Theta rec} / \Delta Z_{th \Theta sin}$

	$\Theta = 180^\circ$	$\Theta = 120^\circ$	$\Theta = 90^\circ$	$\Theta = 60^\circ$	$\Theta = 30^\circ$
$\Delta Z_{th \Theta rec}$ [K/W]	0,02645	0,04099	0,05159	0,06706	0,09217
$\Delta Z_{th \Theta sin}$ [K/W]	0,02007	0,0323	0,04668	0,06381	0,09023

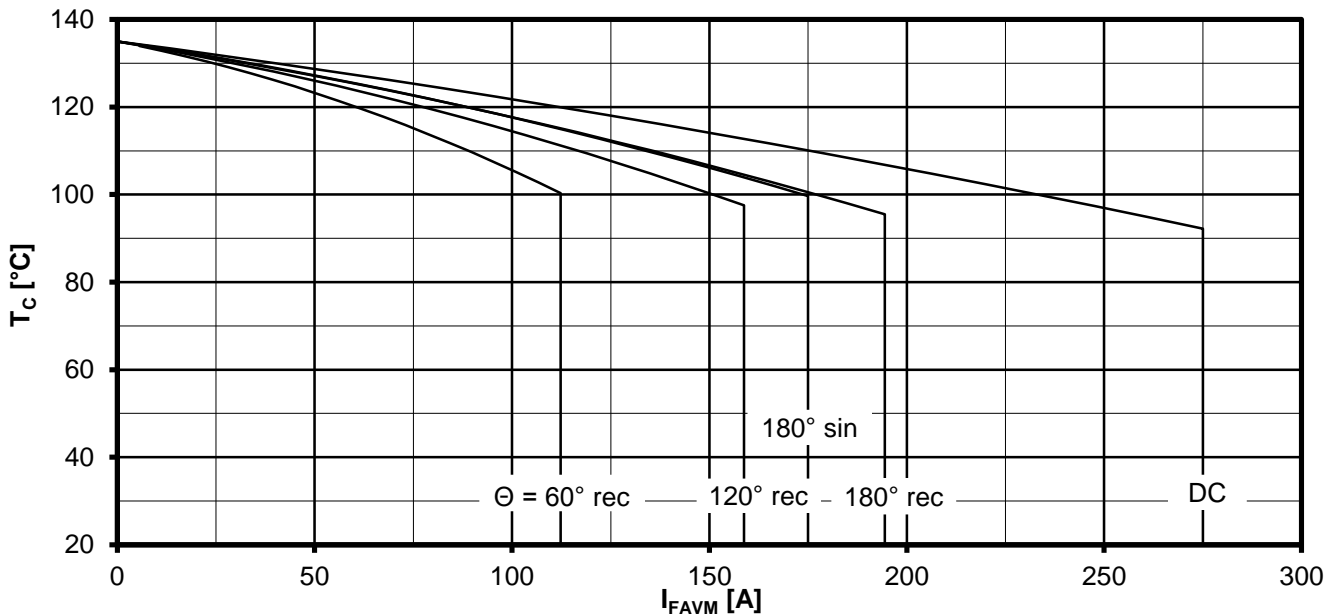
$$Z_{th \Theta rec} = Z_{th DC} + \Delta Z_{th \Theta rec}$$

$$Z_{th \Theta sin} = Z_{th DC} + \Delta Z_{th \Theta sin}$$



Durchlassverlustleistung je Zweig / On-state power loss per arm  $P_{FAV} = f(I_{FAV})$

Parameter: Stromflußwinkel / Current conduction angle  $\Theta$

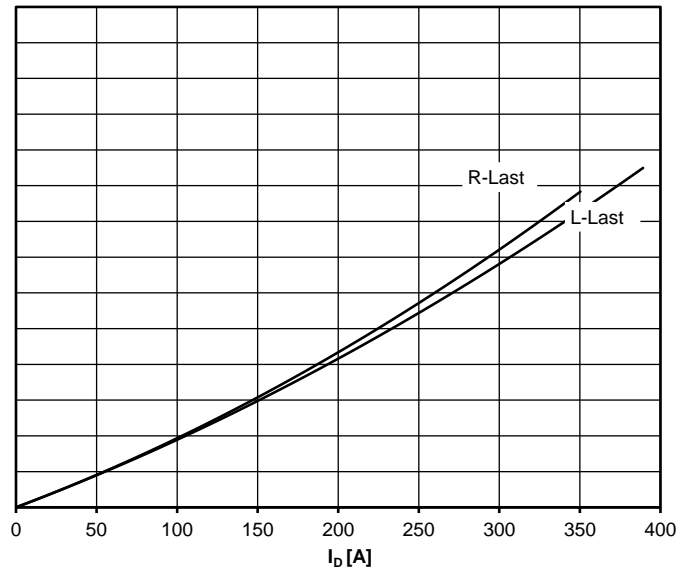
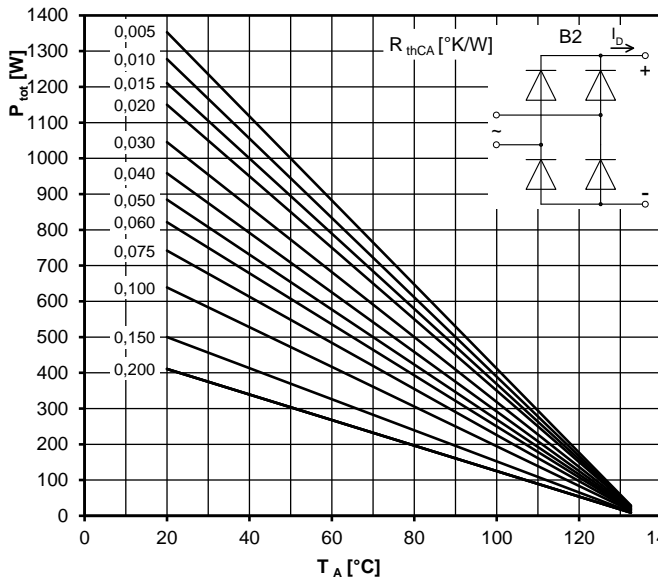
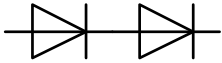


Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature  $T_C = f(I_{FAVM})$

Strombelastung je Zweig / Current load per arm

Berechnungsgrundlage  $P_{TAV}$   
Calculation base  $P_{TAV}$

Parameter: Stromflußwinkel  $\Theta$  / Current conduction angle  $\Theta$



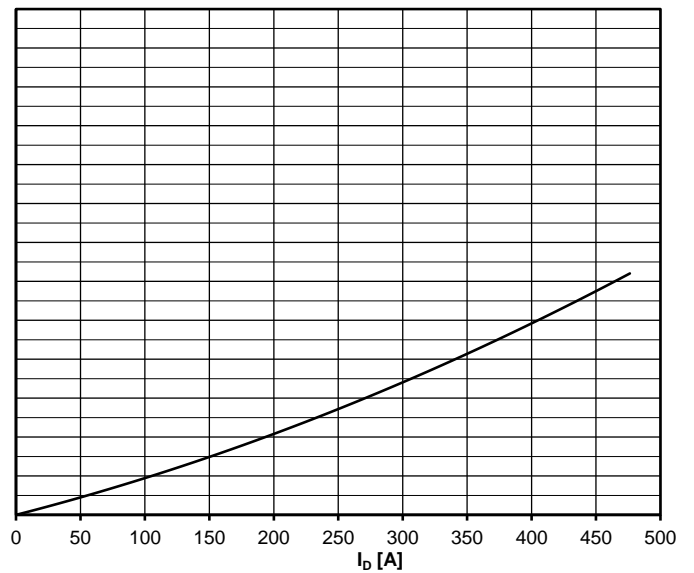
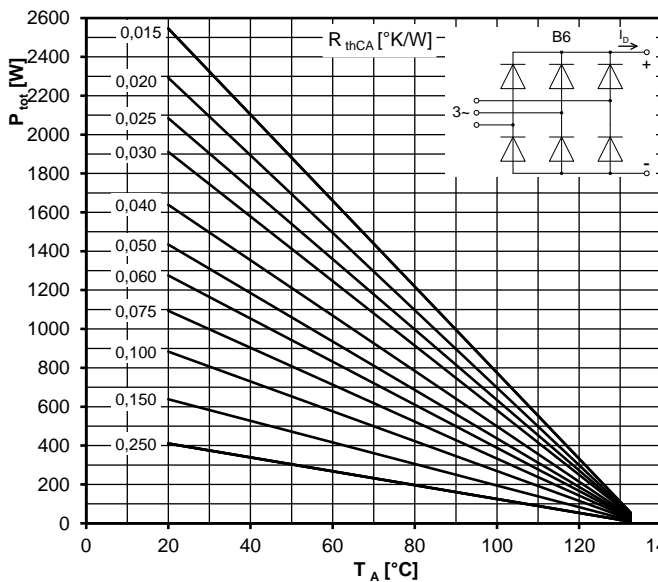
### Höchstzulässiger Ausgangsstrom / Maximum rated output current $I_b$

B2- Zweipuls-Brückenschaltung / Two-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit  $P_{tot}$

Parameter:

Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient  $R_{thCA}$



### Höchstzulässiger Ausgangsstrom / Maximum rated output current $I_b$

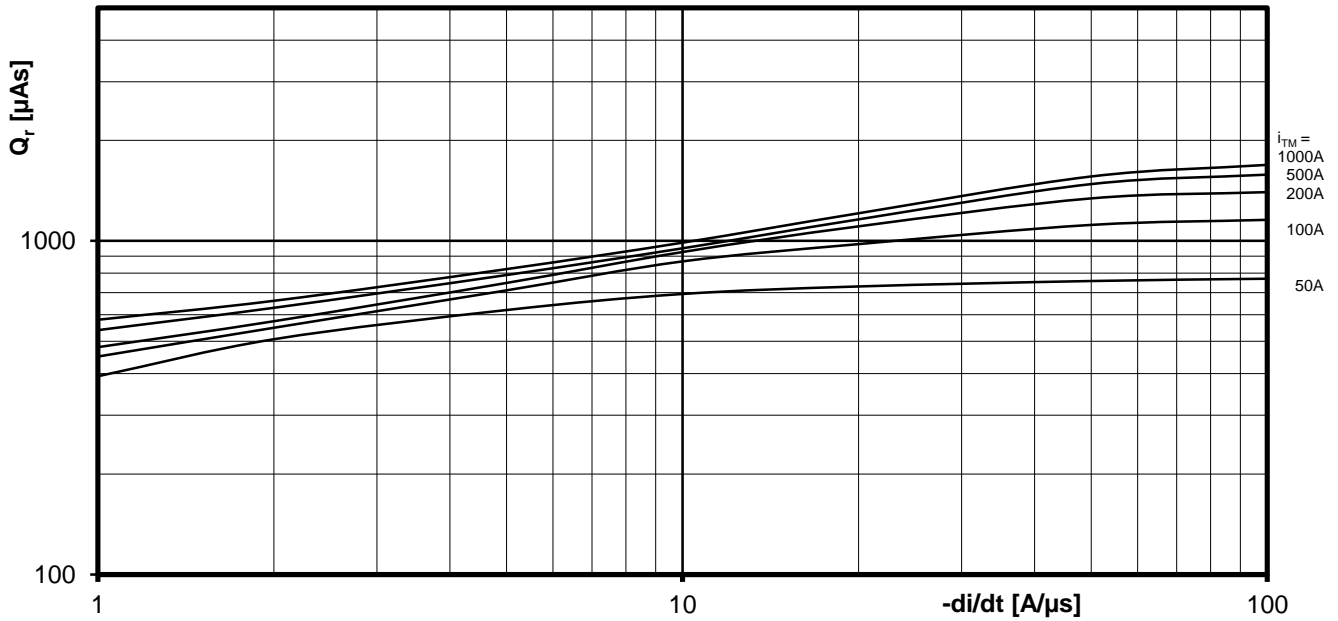
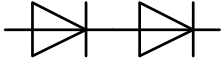
B6- Sechspuls-Brückenschaltung / Six-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit  $P_{tot}$

Parameter:

Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient  $R_{thCA}$

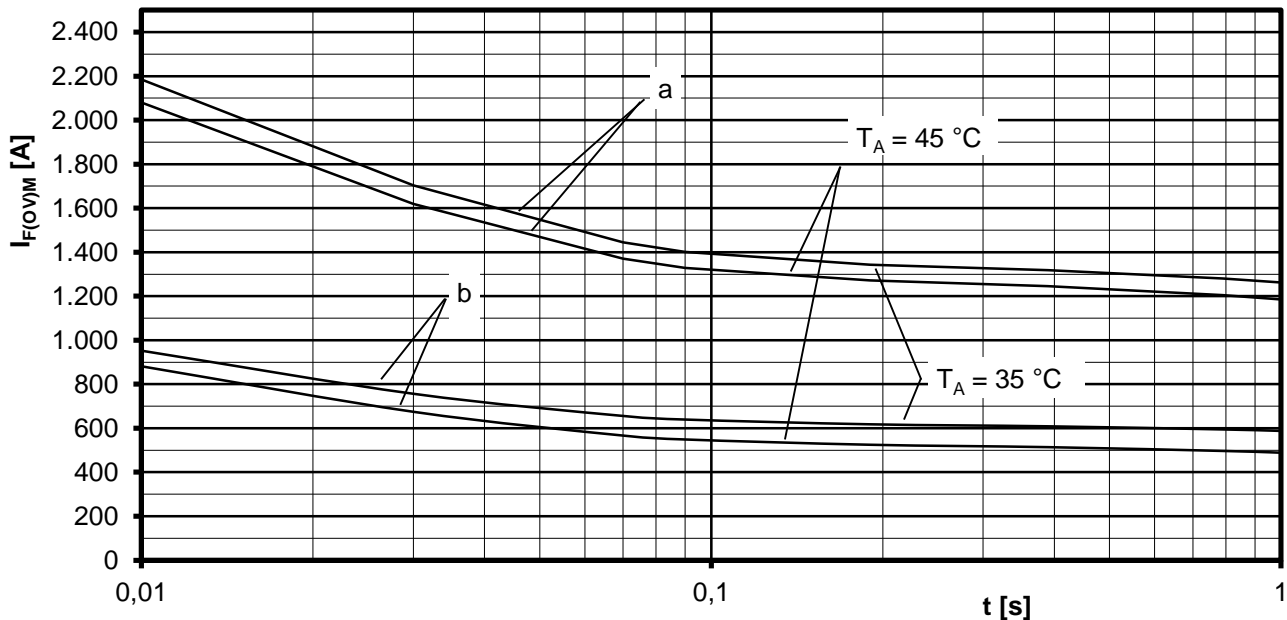




Sperrverzögerungsladung / Recovered charge  $Q_r = f(-di/dt)$

$$T_{vj} = T_{vjmax}, V_R \leq 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$$

Parameter: Durchlaßstrom / On-state current  $i_{FM}$



Grenzstrom je Zweig / Maximum overload on-state current per arm  $I_{F(OV)M} = f(t), V_{RM} = 0,8 V_{RRM}$

a: Leerlauf / No-load conditions

b: Vorlaststrom je Zweig / Pre-load current per arm  $I_{FAV(vor)} = I_{FAVM}$

$T_a = 35^\circ\text{C}$ , verstärkte Luftkühlung / Forced air cooling    Kühlkörper / Heatsink type: KM17 (Papst 4650)

$T_a = 45^\circ\text{C}$ , natürliche Luftkühlung / Natural air cooling    Kühlkörper / Heatsink type: KM17 (60W)